NSN 5961-00-294-9397

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| Inclosure Material: | |
|--|---|
| Metal | |
| Overall Length: | |
| 0.210 inches | |
| Terminal Length: | |
| 0.500 inches | |
| Overall Diameter: | |
| Between 0.209 inches and 0.230 inches | |
| Internal Configuration: | |
| Field effect | |
| Electrode Internally-electrically Connected To Case: | |
| Collector | |
| Internal Junction Configuration: | |
| Np | |
| Mounting Method: | |
| Terminal | |
| Terminal Circle Diameter: | |
| 0.100 inches | |
| Semiconductor Material: | |
| Silicon | |
| Voltage Rating In Volts Per Characteristic: | |
| 40.0 breakdown voltage, drain-to-source, with all other terminals short-ci | rcuited to source and 40.0 breakdown voltage, gate-to-source, |
| with all other terminals short-circuited to source | |
| Current Rating Per Characteristic: | |
| 10.00 milliamperes gate current | |
| Power Rating Per Characteristic: | |
| 1.8 watts collector power dissipation | |
| Maximum Operating Tempurature Per Measurement Point: | |
| 200.0 degrees celsius junction | |
| Terminal Type And Quantity: | |
| 3 uninsulated wire lead | |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |
| No | |
| Fiig: | |
| A110a0 | |